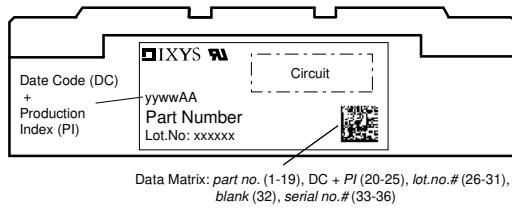


Thyristor

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
$V_{RSM/DSM}$	max. non-repetitive reverse/forward blocking voltage	$T_{VJ} = 25^\circ\text{C}$			1700	V
$V_{RRM/DRM}$	max. repetitive reverse/forward blocking voltage	$T_{VJ} = 25^\circ\text{C}$			1600	V
$I_{R/D}$	reverse current, drain current	$V_{R/D} = 1600 \text{ V}$ $V_{R/D} = 1600 \text{ V}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 140^\circ\text{C}$		300 20	μA mA
V_T	forward voltage drop	$I_T = 200 \text{ A}$	$T_{VJ} = 25^\circ\text{C}$		1.12	V
		$I_T = 400 \text{ A}$			1.33	V
		$I_T = 200 \text{ A}$ $I_T = 400 \text{ A}$	$T_{VJ} = 125^\circ\text{C}$		1.06 1.31	V
I_{TAV}	average forward current	$T_C = 85^\circ\text{C}$	$T_{VJ} = 140^\circ\text{C}$		260	A
$I_{T(RMS)}$	RMS forward current	180° sine			408	A
V_{T0}	threshold voltage	r_T slope resistance } for power loss calculation only	$T_{VJ} = 140^\circ\text{C}$		0.81	V
	slope resistance				1.23	$\text{m}\Omega$
R_{thJC}	thermal resistance junction to case				0.13	K/W
R_{thCH}	thermal resistance case to heatsink			0.07		K/W
P_{tot}	total power dissipation		$T_C = 25^\circ\text{C}$		880	W
I_{TSM}	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ\text{C}$		8.30	kA
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 \text{ V}$		8.97	kA
		$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 140^\circ\text{C}$		7.06	kA
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 \text{ V}$		7.62	kA
I^2t	value for fusing	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ\text{C}$		344.5	kA^2s
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 \text{ V}$		334.3	kA^2s
		$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 140^\circ\text{C}$		248.9	kA^2s
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 \text{ V}$		241.6	kA^2s
C_J	junction capacitance	$V_R = 400 \text{ V}$ $f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ\text{C}$	366		pF
P_{GM}	max. gate power dissipation	$t_p = 30 \mu\text{s}$	$T_C = 140^\circ\text{C}$		120	W
		$t_p = 500 \mu\text{s}$			60 20	W
P_{GAV}	average gate power dissipation					
$(di/dt)_{cr}$	critical rate of rise of current	$T_{VJ} = 140^\circ\text{C}; f = 50 \text{ Hz}$ repetitive, $I_T = 780 \text{ A}$			100	$\text{A}/\mu\text{s}$
		$t_p = 200 \mu\text{s}; di_G/dt = 0.5 \text{ A}/\mu\text{s};$				
		$I_G = 0.5 \text{ A}; V = \frac{2}{3} V_{DRM}$ non-repet., $I_T = 260 \text{ A}$			500	$\text{A}/\mu\text{s}$
$(dv/dt)_{cr}$	critical rate of rise of voltage	$V = \frac{2}{3} V_{DRM}$	$T_{VJ} = 140^\circ\text{C}$		1000	$\text{V}/\mu\text{s}$
		$R_{GK} = \infty$; method 1 (linear voltage rise)				
V_{GT}	gate trigger voltage	$V_D = 6 \text{ V}$	$T_{VJ} = 25^\circ\text{C}$		2	V
			$T_{VJ} = -40^\circ\text{C}$		3	V
I_{GT}	gate trigger current	$V_D = 6 \text{ V}$	$T_{VJ} = 25^\circ\text{C}$		150	mA
			$T_{VJ} = -40^\circ\text{C}$		220	mA
V_{GD}	gate non-trigger voltage	$V_D = \frac{2}{3} V_{DRM}$	$T_{VJ} = 140^\circ\text{C}$		0.25	V
I_{GD}	gate non-trigger current				10	mA
I_L	latching current	$t_p = 30 \mu\text{s}$	$T_{VJ} = 25^\circ\text{C}$		200	mA
		$I_G = 0.5 \text{ A}; di_G/dt = 0.5 \text{ A}/\mu\text{s}$				
I_H	holding current	$V_D = 6 \text{ V}$ $R_{GK} = \infty$	$T_{VJ} = 25^\circ\text{C}$		150	mA
t_{gd}	gate controlled delay time	$V_D = \frac{1}{2} V_{DRM}$	$T_{VJ} = 25^\circ\text{C}$		2	μs
		$I_G = 0.5 \text{ A}; di_G/dt = 0.5 \text{ A}/\mu\text{s}$				
t_q	turn-off time	$V_R = 100 \text{ V}; I_T = 260 \text{ A}; V = \frac{2}{3} V_{DRM}$ $T_{VJ} = 125^\circ\text{C}$	$di/dt = 10 \text{ A}/\mu\text{s}$ $dv/dt = 50 \text{ V}/\mu\text{s}$ $t_p = 200 \mu\text{s}$	200		μs

Package Y4

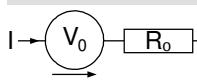
Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
I_{RMS}	RMS current	per terminal			300	A
T_{VJ}	virtual junction temperature		-40		140	°C
T_{op}	operation temperature		-40		125	°C
T_{stg}	storage temperature		-40		125	°C
Weight				150		g
M_D	mounting torque		2.25		2.75	Nm
M_T	terminal torque		4.5		5.5	Nm
$d_{Spp/App}$	creepage distance on surface / striking distance through air	terminal to terminal	14.0	10.0		mm
$d_{Spb/Apb}$		terminal to backside	16.0	16.0		mm
V_{ISOL}	isolation voltage	t = 1 second t = 1 minute	50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA	4800 4000		V V

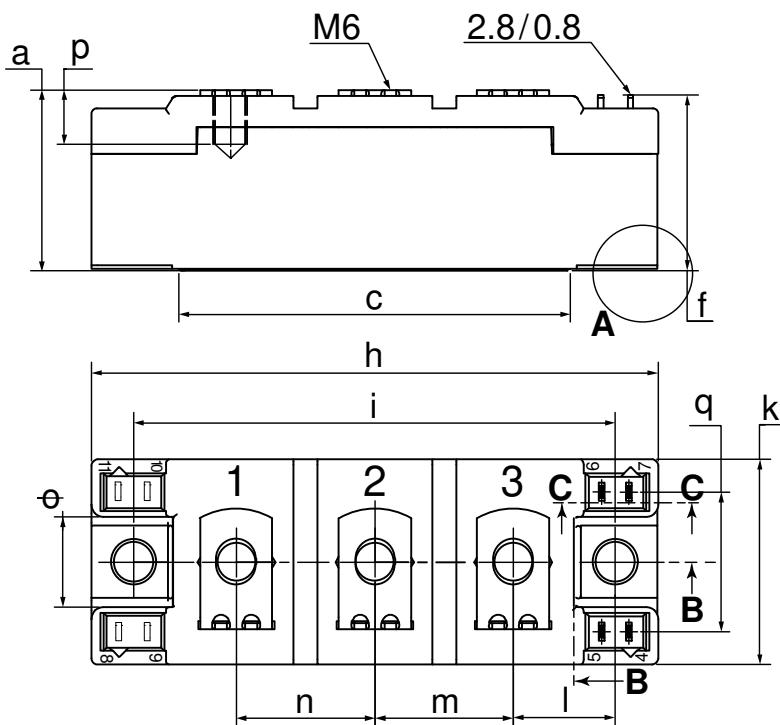

Part description

M = Module
C = Thyristor (SCR)
M = Thyristor
A = (up to 1800V)
260 = Current Rating [A]
P = Phase leg
1600 = Reverse Voltage [V]
YA = Y4-M6

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MCMA260P1600YA	MCMA260P1600YA	Box	6	509785

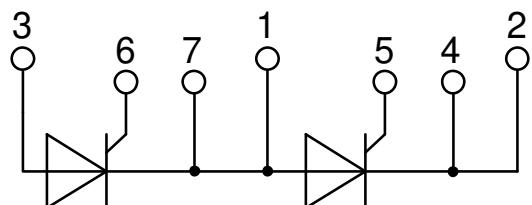
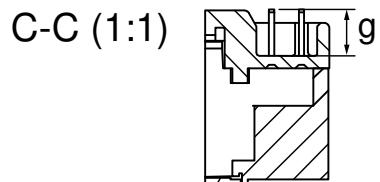
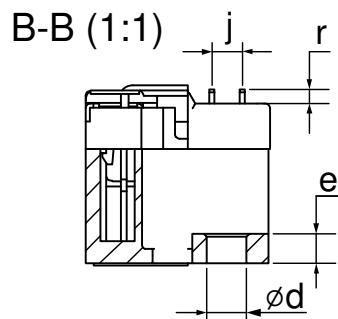
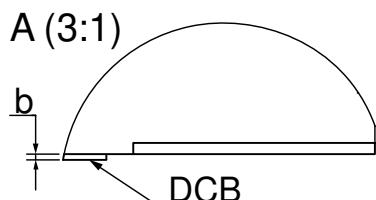
Equivalent Circuits for Simulation
* on die level
 $T_{VJ} = 140$ °C

	Thyristor	
V_0	threshold voltage	0.81
R_0 max	slope resistance *	0.59

Outlines Y4


Dim.	MIN [mm]	MAX [mm]	MIN [inch]	MAX [inch]
a	30.0	30.6	1.181	1.205
b	typ. 0.25		typ. 0.010	
c	64.0	65.0	2.520	2.559
d	6.5	7.0	0.256	0.275
e	4.9	5.1	0.193	0.201
f	28.6	29.2	1.126	1.150
g	7.3	7.7	0.287	0.303
h	93.5	94.5	3.681	3.720
i	79.5	80.5	3.130	3.169
j	4.8	5.2	0.189	0.205
k	33.4	34.0	1.315	1.339
l	16.7	17.3	0.657	0.681
m	22.7	23.3	0.894	0.917
n	22.7	23.3	0.894	0.917
o	14.0	15.0	0.551	0.591
p	typ. 10.5		typ. 0.413	
q	22.8	23.3	0.898	0.917
r	1.8	2.4	0.071	0.041

Optional accessories for modules
Keyed gate/cathode twin plugs with wire length = 350 mm, gate = white, cathode = red
Type ZY 180L (L = Left for pin pair 4/5)
Type ZY 180R (R = Right for pin pair 6/7) } UL 758, style 3751



Thyristor

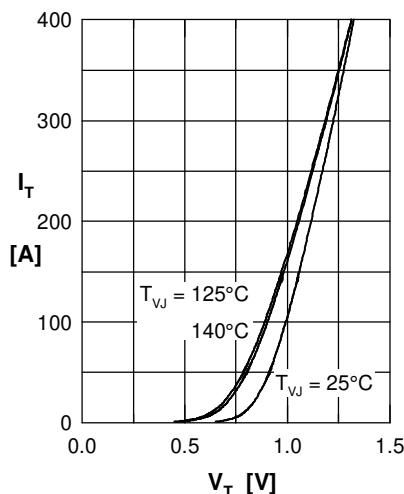


Fig. 1 Forward current vs.
voltage drop per thyristor

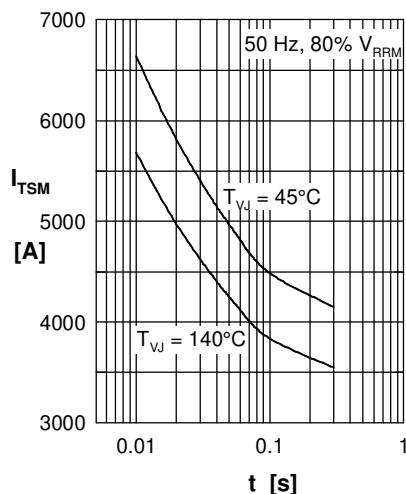


Fig. 2 Surge overload current
vs. time per thyristor

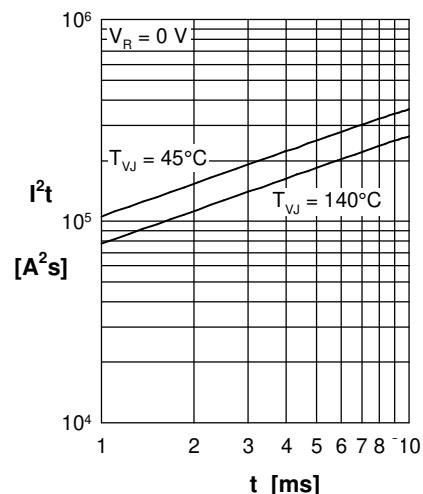


Fig. 3 I^2t vs. time per thyristor

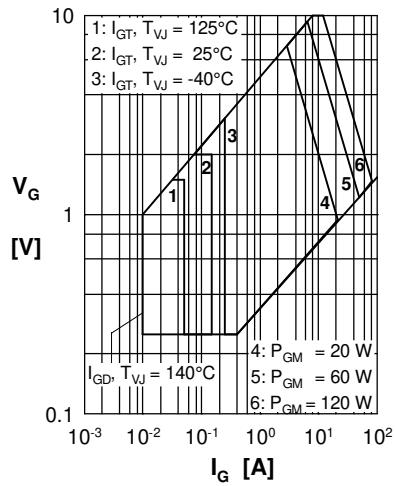


Fig. 4 Gate voltage & gate current

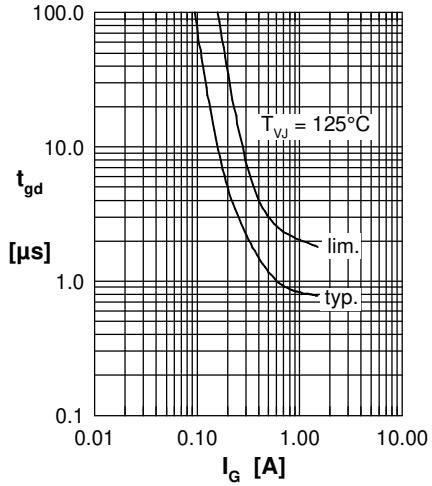


Fig. 5 Gate controlled delay time t_{gd}

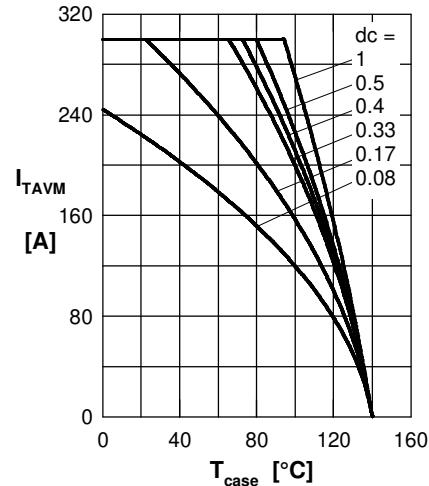


Fig. 6 Max. forward current vs.
case temperature per thy.

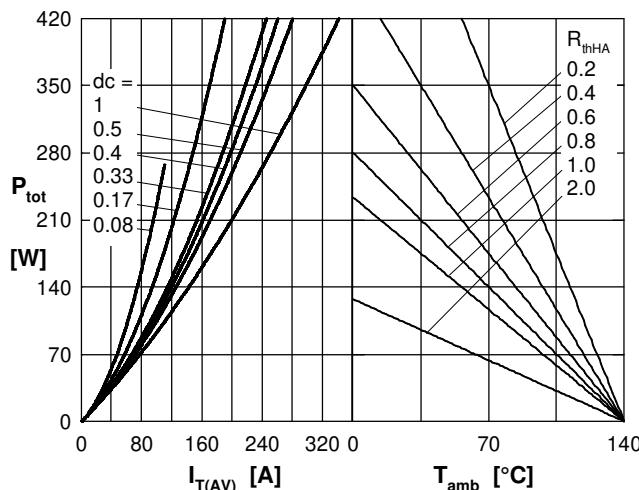


Fig. 7 Power dissipation vs. forward current
and ambient temperature per thyristor

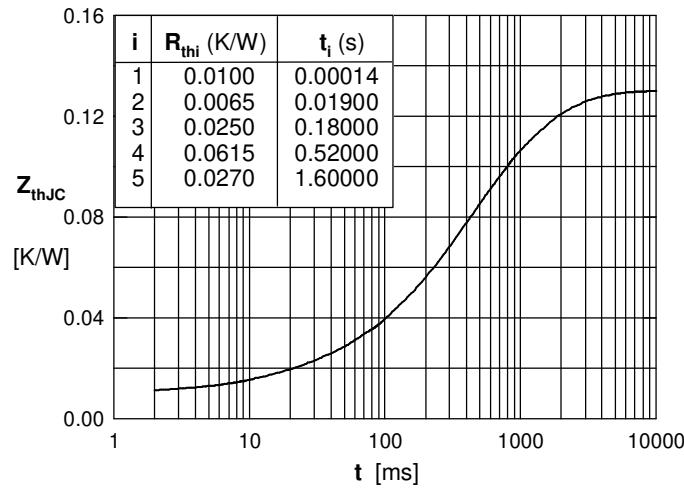


Fig. 8 Transient thermal impedance junction to case
vs. time per thyristor

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